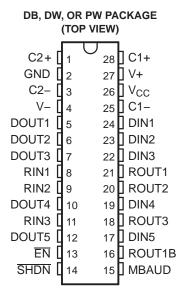
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FEATURES

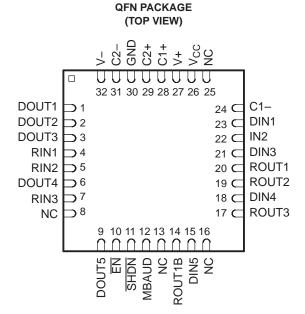
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates With 3-V to 5.5-V V_{CC} Supply
- Operates From 250 kbits/s to 1 Mbit/s
- Low Standby Current . . . 1 μA Typical
- External Capacitors . . . $4 \times 0.1 \mu F$
- Accepts 5-V Logic Input With 3.3-V Supply
- Designed to Be Interchangeable With Maxim MAX3237E
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II



- ESD Protection for RS-232 I/O Pins and Logic Input pins
 - ±15 kV Human-Body Model (HBM)
 - ±8 kV IEC61000-4-2, Contact Discharge
 - ±15 kV IEC61000-4-2, Air-Gap Discharge

APPLICATIONS

- Battery-Powered, Hand-Held, and Portable Equipment
- PDAs and Palmtop PCs
- Notebooks, Sub-Notebooks, and Laptops
- Digital Cameras
- Mobile Phones and Wireless Devices



DESCRIPTION

The MAX3237E consists of five line drivers, three line receivers, and a dual charge-pump circuit with ± 15 -kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3-V to 5.5-V supply. This device operates at data signaling rates of 250 kbit/s in normal operating mode (MBAUD = GND) and 1Mbit/s when MBAUD = V_{CC} . The driver output slew rate is a maximum of 30 V/ μ s.

DESCRIPTION (CONTINUED)

The MAX3237E transmitters are disabled and the outputs are forced into high-impedance state when the device is in shutdown mode ($\overline{SHDN} = GND$) and the supply current falls to less than 1 μ A. Also, during shutdown, the onboard charge pump is disabled; V+ is lowered to V_{CC}, and V- is raised toward GND. Receiver outputs also can be placed in the high-impedance state by setting enable (\overline{EN}) high. ROUT1B remains active all the time, regardless of the \overline{EN} and \overline{SHDN} condition.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





The MAX3237EC is characterized for operation from 0° C to 70° C. The MAX3237EI is characterized for operation from -40° C to 85° C.

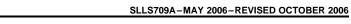
AVAILABLE OPTIONS

T _A	PACKAGED DEVICES
	MAX3237ECDBR
0°C to 70°C	MAX3237ECPWR
0 0 10 70 0	MAX3237ECRHBR (QFN package)
	MAX3237ECDWR
	MAX3237EIDBR
-40°C to 85°C	MAX3237EIPWR
-40 C 10 60 C	MAX3237EIRHBR (QFN package)
	MAX3237EIDWR

FUNCTION TABLE

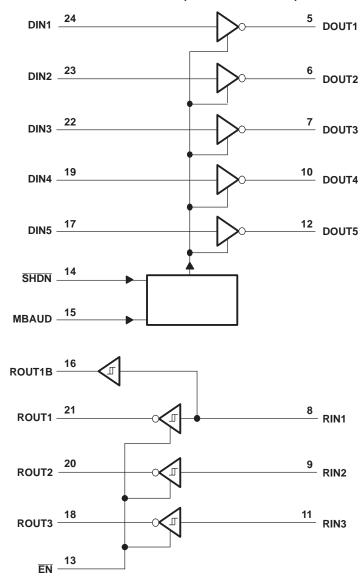
INPUT	S	OUTPUTS		
SHDN	EN	DOUT	ROUT	ROUT1B
0	0	Z ⁽¹⁾	Active	Active
0	1	Z ⁽¹⁾	Z ⁽¹⁾	Active
1	0	Active	Active	Active
1	1	Active	Z ⁽¹⁾	Active

(1) Z = high impedance (off)





LOGIC DIAGRAM (POSITIVE LOGIC)



MAX3237E 3-V TO 5.5-V MULTICHANNEL RS-232 1-MBit/s LINE DRIVER/RECEIVER





Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾		-0.3	6	V
V+	Positive-output supply voltage range (2)		-0.3	7	V
V-	Negative-output supply voltage range (2)		0.3	-7	V
V+ - V-	Supply voltage difference ⁽²⁾			13	V
V	Input voltage range	Driver (SHDN, MBAUD, EN)	-0.3	6	V
VI		Receiver	-25	25	V
V	Output valtage range	Driver		13.2	V
Vo	Output voltage range	Receiver	-0.3	V _{CC} + 0.3	V
	Short-circuit duration	DOUT to GND		Unlimited	
θ_{JA}	Package thermal impedance ⁽³⁾			62	°C/W
	Lead temperature 1,6 mm (1/16 in) from case for 10 s			260	°C
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Recommended Operating Conditions(1)

See Figure 5

				MIN	NOM	MAX	UNIT
	Supply voltage	V _{CC} = 3.3 V	3	3.3	3.6	V	
	Supply voltage			4.5	5	5.5	V
V	V Driver and central high level input valtage	DIN, SHDN, MBAUD, EN	V _{CC} = 3.3 V	2		5.5	V
V _{IH}	Driver and control high-level input voltage DIN, SHDN, MBAUD, EN		$V_{CC} = 5 V$	2.4		5.5	V
V_{IL}	Driver and control low-level input voltage	DIN, SHDN, MBAUD, EN		0		0.8	V
VI	Receiver input voltage			-25		25	V
т	Operating free air temperature	On another two states are and any		0		70	°C
IA	Operating free-air temperature		MAX3237EI	-40		85	C

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3 V to 5 V.

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETE	TEST CONDITIONS	MIN TYP ⁽²⁾	MAX	UNIT	
I _I	Input leakage current	DIN, SHDN, MBAUD, EN		9	18	μΑ
			No load, $\overline{SHDN} = V_{CC}$	0.5	2	mA
loo	Supply current		SHDN = GND	1	10	μΑ
Icc	$(T_A = 25^{\circ}C)$	Shutdown supply current	SHDN = RIN = GND, DIN = GND or V _{CC}	10	300	nA

All voltages are with respect to network GND.

⁽³⁾ The package thermal impedance is calculated in accordance with JESD 51-7.

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3 V to 5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.



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DRIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

PARAMETER		TEST CONDITIONS			TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	DIN = GND	5	5.4		V
V_{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GND,	$DIN = V_{CC}$	-5	-5.4		V
I _{IH}	High-level input current	$V_I = V_{CC}$			±0.01	±1	μΑ
I _{IL}	Low-level input current	V _I at GND			±0.01	±1	μΑ
Ios	Short-circuit output current ⁽³⁾	V _{CC} = 3.6 V or 3.3 V,	V _O = 0 V			±60	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V	300	50k		Ω

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3 V to 5 V.

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

I	PARAMETER		TEST CONDITIONS		MIN	TYP ⁽²⁾	MAX	UNIT	
		C _L = 1000 pF, MBAUD = GND			250				
	Maximum data rate	$C_L = 1000 \text{ pF},$ $V_{CC} = 4.5 \text{ V to } 5.5 \text{ V},$ $MBAUD = V_{CC}$	$R_L = 3 \text{ k}\Omega$, 1 DIN switching, See Figure 1		1000			kbit/s	
		C_L = 250 pF, V_{CC} = 3 V to 4.5 V, MBAUD = V_{CC}		1000					
t _{sk(p)}	Pulse skew ⁽³⁾	C_L = 150 pF to 2500 pF, MBAUD = V_{CC} or GND, S				100		ns	
	Slew rate	Slew rate, $V_{CC} = 3.3 \text{ V}$,	$= 3.3 \text{ V},$ $C_1 = 150 \text{ pF to } 1000 \text{ pF}$	MBAUD = GND	6		30		
SR(tr)	transition region	$R_L = 3 k\Omega$ to $7 k\Omega$,	OL = 130 pr to 1000 pr	$MBAUD = V_{CC}$	24		150	V/μs	
	(see Figure 1)	(see Figure 1) $T_A = 25^{\circ}C$		$C_L = 150 \text{ pF to } 2500 \text{ pF},$	MBAUD = GND	4		30	

All typical values are at $V_{CC} = 3.3$ V or $V_{CC} = 5$ V, and $T_A = 25^{\circ}$ C. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3 V to 5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

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RECEIVER SECTION

Electrical Characteristics(1)

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 5)

	PARAMETER	TEST CONDITIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$	$V_{CC} - 0.6$	V _{CC} - 0.1		٧
V_{OL}	Low-level output voltage	I _{OL} = 1 mA			0.4	٧
	Desitive gains input threehold voltage	$V_{CC} = 3.3 \text{ V}$		1.5	2.4	٧
V _{IT+}	Positive-going input threshold voltage	V _{CC} = 5 V		2	2.4	V
V	Negative going input threehold voltage	V _{CC} = 3.3 V	0.6	1.1		V
V _{IT}	Negative-going input threshold voltage	V _{CC} = 5 V	0.8	1.5		V
V _{hys}	Input hysteresis (V _{IT+} – V _{IT-})			0.5		V
l _{oz}	Output leakage current	EN = V _{CC}		±0.05	±10	μΑ
r _i	Input resistance	$V_1 = \pm 3 \text{ V to } \pm 25 \text{ V}$	3	5	7	kΩ

Switching Characteristics⁽¹⁾

over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	TYP ⁽²⁾	UNIT
t_{PLH}	Propagation delay time, low- to high-level output	C _L = 150 pF, See Figure 3	150	ns
t _{PHL}	Propagation delay time, high- to low-level output	C _L = 150 pF, See Figure 3	150	ns
t _{en}	Output enable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	2.6	μs
t _{dis}	Output disable time	$C_L = 150 \text{ pF}, R_L = 3 \text{ k}\Omega, \text{ See Figure 4}$	2.4	μs
t _{sk(p)}	Pulse skew ⁽³⁾	See Figure 3	50	ns

ESD Protection

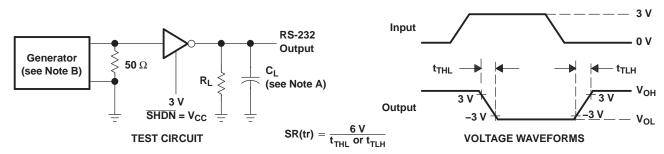
PIN	TEST CONDITIONS	TYP	UNIT
	НВМ	±15	
DIN, RIN, ROUT	IEC61000-4-2, Contact Discharge	±8	kV
	IEC61000-4-2, Air-Gap Discharge	±15	

⁽¹⁾ Test conditions are C1–C4 = 0.1 mF at V_{CC} = 3 V to.5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C.

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 3 V to 5 V. (2) All typical values are at V_{CC} = 3.3 V or V_{CC} = 5 V, and T_A = 25°C. (3) Pulse skew is defined as $|t_{PLH} - t_{PHL}|$ of each channel of the same device.

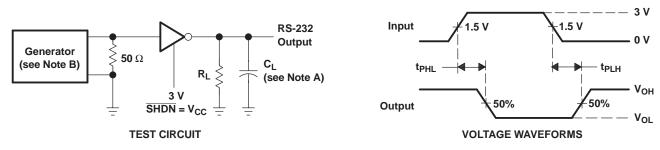


PARAMETER MEASUREMENT INFORMATION



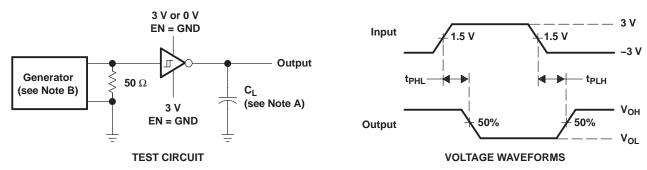
- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_{O} = 50 Ω , 50% duty cycle, t_{f} \leq 10 ns, t_{f} \leq 10 n

Figure 1. Driver Slew Rate



- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: PRR = 250 kbit/s, Z_{O} = 50 Ω , 50% duty cycle, t_{f} \leq 10 ns, t_{f} \leq 10 ns, t_{f}

Figure 2. Driver Pulse Skew

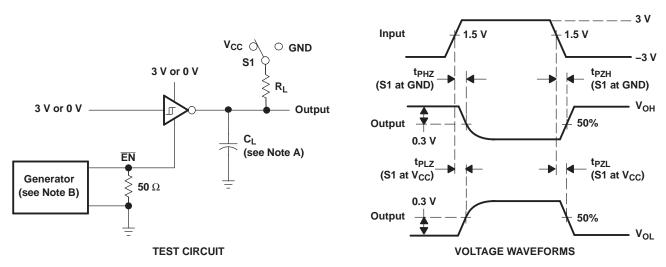


- NOTES: A. C_L includes probe and jig capacitance.
 - B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.

Figure 3. Receiver Propagation Delay Times



PARAMETER MEASUREMENT INFORMATION (continued)



NOTES: A. C_L includes probe and jig capacitance.

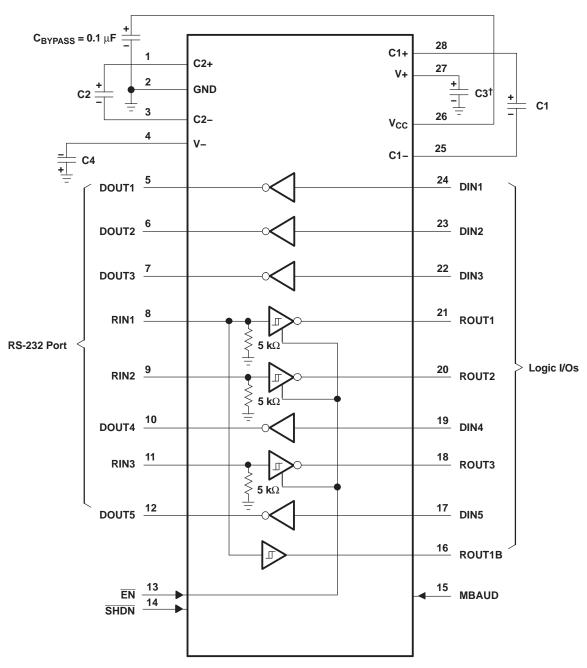
- B. The pulse generator has the following characteristics: $Z_O = 50 \Omega$, 50% duty cycle, $t_f \le 10$ ns. $t_f \le 10$ ns.
- C. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- D. t_{PZL} and t_{PZH} are the same as t_{en} .

Figure 4. Receiver Enable and Disable Times





APPLICATION INFORMATION



 † C3 can be connected to V_{CC} or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

V_{CC} vs CAPACITOR VALUES

V _{CC}	C1	C2, C3, and C4
$\begin{array}{c} 3.3 \text{ V} \pm 0.15 \text{ V} \\ 3.3 \text{ V} \pm 0.3 \text{ V} \\ 5 \text{ V} \pm 0.5 \text{ V} \\ 3 \text{ V to 5.5 V} \end{array}$	0.1 μF 0.22 μF 0.047 μF 0.22 μF	0.1 μF 0.22 μF 0.33 μF 1 μF

Figure 5. Typical Operating Circuit and Capacitor Values



PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MAX3237ECDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDBG4	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDBRG4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDW	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDWG4	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDWR	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECDWRG4	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECPW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECPWG4	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECPWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237ECPWRG4	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDBG4	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDBRG4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDW	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDWG4	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDWR	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIDWRG4	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIPW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIPWG4	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIPWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX3237EIPWRG4	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

 $^{^{(1)}}$ The marketing status values are defined as follows:



PACKAGE OPTION ADDENDUM

6-Dec-2006

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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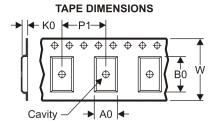




11-Mar-2008

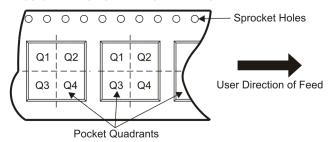
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

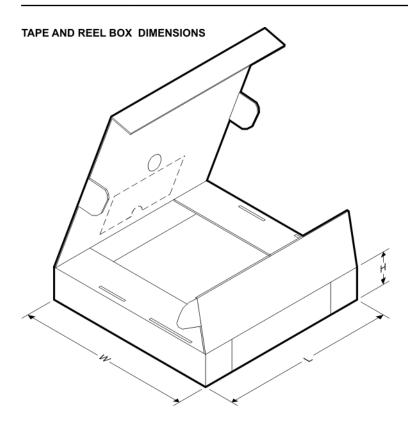
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX3237ECDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3237ECDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX3237ECPWR	TSSOP	PW	28	2000	330.0	16.4	7.1	10.4	1.6	12.0	16.0	Q1
MAX3237EIDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX3237EIDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX3237EIPWR	TSSOP	PW	28	2000	330.0	16.4	7.1	10.4	1.6	12.0	16.0	Q1





*All dimensions are nominal

Device Package T		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX3237ECDBR	SSOP	DB	28	2000	346.0	346.0	33.0
MAX3237ECDWR	SOIC	DW	28	1000	346.0	346.0	49.0
MAX3237ECPWR	TSSOP	PW	28	2000	346.0	346.0	33.0
MAX3237EIDBR	SSOP	DB	28	2000	346.0	346.0	33.0
MAX3237EIDWR	SOIC	DW	28	1000	346.0	346.0	49.0
MAX3237EIPWR	TSSOP	PW	28	2000	346.0	346.0	33.0

PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

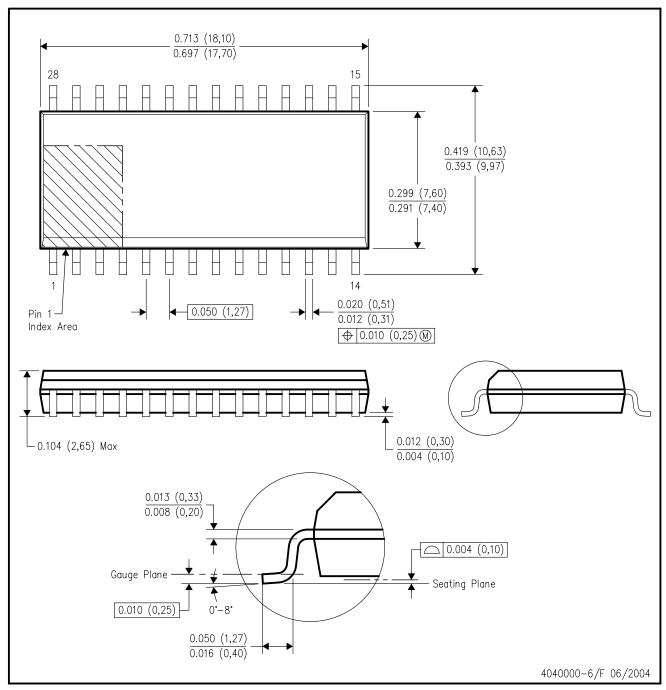
B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

DW (R-PDSO-G28)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AE.



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